V-Cell Mono Series

6" Mono c-Si Solar Cell

Physical Characteristics

156mm X 156mm ± 0.5mm

 $180 \mu m \pm 20 \mu m$, $200 \mu m \pm 30 \mu m$

Distance between bus bars : 39 mm

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Aluminum back surface field

Alkaline texturized surface with silicon nitride

 $4 \times 1.1 \text{ mm} \pm 0.1 \text{ mm}$ wide segmented bus bars

4 X 3 soldering pads, 2.1 mm \pm 0.15 mm wide bus bars

Diagonal: 200mm

anti-reflecting coating

TSS64TN

Dimensions

Thickness(Si)

Front(-)

Back(+)



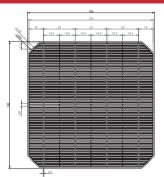


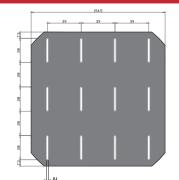
Features

- -High Cell-To- Module ratio through precise cell conversion efficiency sorting, classified efficiency grade by both minimum power and current.
- -Excellent electrical long-term stability and reliability by using of best raw materials and through strict quality inspection control.
- -Low breakage rate by using high qualified and stable wafers.
- -High quality homogeneous appearance by sorting into defined color classes.
- -100% screened for reverse current and shunt resistance.
- -Excellent passivation quality of the rear side compared to the traditional solar cell is clearly visible in the long wavelength regime.
- -The best solution for PV module with above 280W outputs.

Quality Control and Professional Service

- -Regular calibration of test equipment using Fraunhofer ISE reference cell. -Environmental friendly due to REACH-SVHC and RoHS compliances.
- -Professional on-site service and support for module certification.
- -Regular light source AAA class calibration for stable conversion efficiency. -Lowest LID by periodic monitoring and superior wafer incoming control.





Electrical Characteristics

Efficiency Code		210	208	206	204	202	200	198
Efficiency	Eff(%)	21.00	20.80	20.60	20.40	20.20	20.00	19.80
Power	Pmpp(W)	5.02	4.97	4.92	4.87	4.83	4.78	4.73
Max. Power Current	Impp(A)	8.775	8.744	8.714	8.684	8.652	8.627	8.591
Short Circuit Current	Isc(A)	9.314	9.287	9.260	9.234	9.206	9.183	9.153
Max. Power Voltage	Vmpp(V)	0.572	0.569	0.565	0.561	0.558	0.554	0.551
Open Circuit Voltage	Voc(V)	0.669	0.666	0.663	0.660	0.657	0.653	0.650

Standard test condition: AM1.5, 1000W/m², 25°c Average accuracy of all tests is +/-1.5% rel.



Temperature Coefficients

Current Temperature Coefficient	0.043%/K		
Voltage Temperature Coefficient	B(VOC)	-0.30 %/K	
Power Temperature Coefficient	γ(Pmax)	-0.38 %/K	

Standard test condition: AM1.5, 1000W/m², 25°c

Processing Recommendations

Solder Joint

Copper ribbons coated with 15~25µm: 62%Sn/36%Pb/2%Ag or 60%Sn/40%Pb

Standard test condition: AM1.5, 1000W/m², 25°c

Solderability

Peel Strength Minimum

>1.25 N/mm

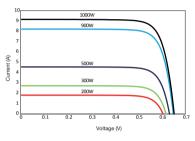
Soldering results may differ due to different flux, ribbons, soldering methods, and parameters.

Qualifications and Certificates

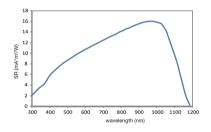


RoHS Compliance SVHC tested

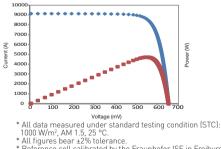
Typical Current-Voltage Curve



Typical Spectral Response

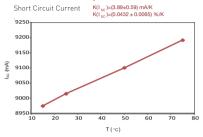


Typical IV-Power Curve

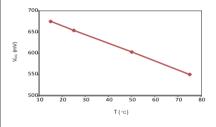


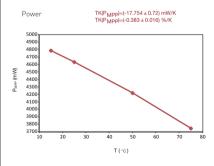
* Reference cell calibrated by the Fraunhofer ISE in Freiburg.

Calculated Temperature Coefficients



Open Circuit Voltage TK (Voc)=(-1.980 ± 0.039) mV / K TK (Voc)=(-0.303 ± 0.0059) % / K





TSEC Corporation

Taipei Headquarters

8F, No.225, Sec. 3, Beixin Rd., Xindian Dist., New Taipei City 23143, Taiwan, R.O.C t 886 2 2912 2199 f 886 2 2917 5399 m sales@tsecpv.com

Hsinchu Plant

No.85, Guangfu N. Rd., Hukou Township, Hsinchu County 30351, Taiwan, R.O.C. (Hsinchu Industrial Park) t 886 3 696 0707 f 886 3 696 0708 D200_M0 Specifications are subject to change without prior notice. TSEC reserves the rights of final interpretation and revision of datasheet. **Preliminary version-January 2016**